

SIM/Smart Card Level Translators in µMAX

General Description

The MAX1740/MAX1741 subscriber identity module (SIM)/smart card level translators provide level shifting and electrostatic discharge (ESD) protection for SIM and smart card ports. These devices integrate two unidirectional level shifters for the reset and clock signals, a bidirectional level shifter for the serial data stream, and ±10kV ESD protection on all card contacts.

The MAX1740 includes a SHDN control input to aid insertion and removal of SIM and smart cards, while the MAX1741 includes a system-side data driver to support system controllers without open-drain outputs. The logic supply voltage range is +1.425V to +5.5V for the "controller side" and +2.25V to +5.5V for the "card side." Total supply current is 2.5µA max. Both devices automatically shut down when either power supply is removed. For a complete SIM-card interface, combine the MAX1740/MAX1741 with the MAX1686H 0V/3V/5V regulated charge pump.

The MAX1740/MAX1741 are available in ultra-small 10pin µMAX packages that are only 1.09mm high and half the area of an 8-pin SO.

The MAX1740/MAX1741 are compliant with GSM test specifications 11.11 and 11.12.

Applications

SIM Interface in GSM Cellular Telephones **Smart Card Readers** Logic Level Translation SPI™/QSPI™/MICROWIRE™ Level Translation

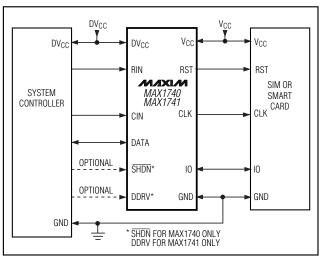
Features

- ♦ SIM/Smart Card Level Shifting
- ♦ ±10kV ESD Card Socket Protection
- **♦** Allows Level Translation with DV_{CC} ≥ V_{CC} or $DVCC \leq VCC$
- ♦ Automatically Shuts Down When Either Supply Is Removed
- **♦ Card Contacts Actively Pulled Low During Shutdown**
- ♦ +1.425V to +5.5V Controller Voltage Range
- ♦ +2.25V to +5.5V Card Voltage Range
- ♦ 2.5µA (max) Total Quiescent Supply Current
- ♦ 0.01µA Total Shutdown Supply Current
- ♦ Ultra-Small 10-Pin µMAX Package
- ♦ Compliant with GSM Test Specifications 11.11 and 11.12

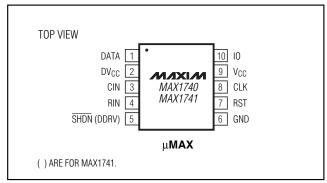
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX1740EUB	-40°C to +85°C	10 μMAX
MAX1741EUB	-40°C to +85°C	10 μMAX

Typical Operating Circuit



Pin Configuration



SPI and QSPI are trademarks of Motorola, Inc. MICROWIRE is a trademark of National Semiconductor Corp.

MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

$\begin{array}{llllllllllllllllllllllllllllllllllll$	Operating Temperature Range40°C to +85°C Storage Temperature Range65°C to +150°C Junction Temperature+150°C Lead Temperature (soldering, 10s)+300°C
10-Pin µMAX (derate 5.6mW/°C above +70°C)444mW	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(Figure 1, DV_{CC} = +1.8V, V_{CC} = +3.0V or +5.0V, \overline{SHDN} = DV_{CC}, CIN = RIN = GND or DV_{CC}, IO = V_{CC}, DATA = DDRV = DV_{CC}, C_{IO} = C_{CLK} = C_{RST} = C_{DATA} = 30pF, T_A = 0°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
POWER SUPPLIES	<u>'</u>						
DV _{CC} Operating Range	DVCC		1.425		5.5	V	
V _{CC} Operating Range	V _{CC}		2.25		5.5	V	
		CIN static			1		
DV _{CC} Operating Current	IDVCC	CIN clocked at 1.625MHz from GND to DV _{CC} with 50% duty cycle		8		μА	
		CIN clocked at 3.25MHz from GND to DV _{CC} with 50% duty cycle		16			
		CIN static			1.5	μΑ	
V _{CC} Operating Current	lvcc	CIN clocked at 1.625MHz from GND to DV _{CC} with 50% duty cycle		0.5			
		CIN clocked at 3.25MHz from GND to DV _{CC} with 50% duty cycle		1		mA	
Total Shutdown Current	I _{SHDN}	I _{OFF} = I _{VCC} + I _{DVCC} , SHDN = GND (MAX1740 only), or DV _{CC} = GND or V _{CC} = GND		0.01	2	μА	
CIN, RIN, SHON, DDRV LOGIC	INPUTS						
Digital Input Low Threshold	VIL		0.2 • DV _{CC}	;		V	
Digital Input High Threshold	VIH			0.	7 • DV _{CC}	V	
Input Leakage Current				0.01	1	μΑ	
CLK, RST OUTPUTS							
Digital Output Low Level	VoL	ISINK = 200µA			0.4	V	
Digital Output High Level	V _{OH}	I _{SOURCE} = 20µA	0.9 • V _C C			V	
Digital Output High Level	VOH	I _{SOURCE} = 200µA	0.8 • V _C C			V	
DATA INPUT/OUTPUT							
DATA Pull-Up Resistance	R _{DATA}	Between DATA and DV _{CC}	13	20	28	kΩ	
Input Low Threshold	VIL(DATA)	(Note 1)	0.3			V	
Input High Threshold	VIH(DATA)	(Note 2)		D	V _{CC} - 0.6	V	
Input Low Current	lıL	V _{CC} = 5.0V			1	mA	
Input High Current	I _{IH}				2	μA	

ELECTRICAL CHARACTERISTICS (continued)

(Figure 1, DV_{CC} = +1.8V, V_{CC} = +3.0V or +5.0V, $\overline{\text{SHDN}}$ = DV_{CC}, CIN = RIN = GND or DV_{CC}, IO = V_{CC}, DATA = DDRV = DV_{CC}, CIO = C_{CLK} = C_{RST} = C_{DATA} = 30pF, **T_A** = 0°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Output Low Level		IO = GND, I _{SINK} = 100μA				0.4	V
	VOL(DATA)	$DV_{CC} = 3.0V$, $IO = GN$	ND, I _{SINK} = 200μA			0.4	V
	V	I _{SOURCE} = 10µA		0.7 • DV _{CC}	;		V
Output High Level	VOH(DATA)	DVCC = 3.0V, ISOURCE	= 20μΑ	0.7 • DV _{CC}	;		V
IO INPUT/OUTPUT				1		•	
IO Pull-Up Resistance	Rio	Between IO and V _{CC}		6.5	10	14	kΩ
Input Low Threshold	V _{IL(IO)}	I _{IL(MAX)} = 1mA (Note	1)	0.3			V
Input High Threshold	V _{IH} (IO)	$I_{IH(MAX)} = \pm 20\mu A$ (Not	te 2)			0.7 • V _C C	V
Input Low Current	I _{IL}					1	mA
Input High Current	lіН					20	μΑ
Output Low Level	V _{OL(IO)}	DATA = GND or DDRV = GND, I _{SINK} = 200µA				0.4	V
Output High Level	V _{OH} (IO)	ISOURCE = 20µA	0.8 • V _C C			V	
SHUTDOWN OUTPUT LEVEL	_S			1		-	
		$I_{SINK} = 200\mu A, \overline{SHDN}$ RIN = DV _{CC} (MAX174	= GND, DATA = CIN = 0 only)			0.4	V
Shutdown Output Levels (IO, CLK, RST)		$\begin{split} & S_{INK} = 200\mu\text{A}, DV_{CC} = \text{GND}, \overline{\text{SHDN}} \\ & (\text{MAX1740}) = \text{DDRV} (\text{MAX1741}) = \text{DATA} = \\ & \text{CIN} = \text{RIN} = \text{DV}_{CC} \\ & S_{INK} = 200\mu\text{A}, V_{CC} = \text{GND}, \overline{\text{SHDN}} \\ & (\text{MAX1740}) = \text{DDRV} (\text{MAX1741}) = \text{DATA} = \\ & \text{CIN} = \text{RIN} = \text{DV}_{CC} \end{split}$				0.4	V
						0.4	V
TIMING							
Maximum CLK Frequency (Notes 3, 4)		V _{CC} = 2.7V to 5.5V	$DV_{CC} = 2.7V$	5			
			DV _{CC} = 2.25V	5			MHz
			$DV_{CC} = 1.7V$	5			
	fclk		DV _{CC} = 1.425V	3.5			
(,		V _{CC} = 2.25V to 3.6V	DV _{CC} = 2.25V	4			
			DV _{CC} = 1.7V	4			
		DV _{CC} = 1.425V		3.5			

ELECTRICAL CHARACTERISTICS

(Figure 1, DV $_{CC}$ = +1.8V, V $_{CC}$ = +3.0V or +5.0V, \overline{SHDN} = DV $_{CC}$, CIN = RIN = GND or DV $_{CC}$, IO = V $_{CC}$, DATA = DDRV = DV $_{CC}$, CIO = C $_{CLK}$ = C $_{RST}$ = C $_{DATA}$ = 30pF, T $_{A}$ = -40°C to +85°C, unless otherwise noted.) (Note 5)

PARAMETER	SYMBOL	CONDITIONS	MIN	MAX	UNITS
POWER SUPPLIES					
DV _{CC} Operating Range	DV _{CC}		1.425	5.5	V
V _{CC} Operating Range	Vcc		2.25	5.5	V
DV _{CC} Operating Current	IDVCC	CIN static		1	μΑ
V _{CC} Operating Current	lvcc	CIN static		1.5	μΑ
Total Shutdown Current	loff	I _{OFF} = I _{VCC} + I _{DVCC} , SHDN = GND (MAX1740 only), or DV _{CC} = GND or V _{CC} = GND		2	μΑ
CIN, RIN, SHDN, DDRV LOGIC	INPUTS				
Digital Input Low Threshold	VIL		0.2 • DV _{CC}		V
Digital Input High Threshold	VIH			0.75 • DV _{CC}	V
Input Leakage Current				1	μΑ
CLK, RST OUTPUTS					
Digital Output Low Level	V _{OL}	I _{SINK} = 200µA		0.4	V
Digital Output High Level	Voн	I _{SOURCE} = 20µA	0.9 • V _{CC}		V
Digital Output High Level	VOH	ISOURCE = 200µA	0.8 • V _{CC}		
DATA INPUT/OUTPUT					
DATA Pull-Up Resistance	RDATA	Between DATA and DV _{CC}	13	28	kΩ
Input Low Threshold	VIL(DATA)	(Note 1)	0.3		V
Input High Threshold	VIH(DATA)	(Note 2)		DV _{CC} - 0.6	V
Input Low Current	I _{IL}	$V_{CC} = 5.0V$		1	mA
Input High Current	lін			2	μΑ
Output Low Level	VOL(DATA)	$IO = GND$, $I_{SINK} = 100\mu A$		0.4	V
Output Low Lovei	VOL(DATA)	$DV_{CC} = 3.0V$, $IO = GND$, $I_{SINK} = 200\mu A$		0.4	V
Output High Level	VOLUBATAN	ISOURCE = 10µA	0.7 • DV _{CC}		V
Output riigir Level	VOH(DATA)	$DV_{CC} = 3.0V$, $I_{SOURCE} = 20\mu A$	0.7 • DV _{CC}		V
IO INPUT/OUTPUT					
IO Pull-Up Resistance	Rio	Between IO and V _{CC}	6.5	14	kΩ
Input Low Threshold	VIL(IO)	$I_{IL(MAX)} = 1mA \text{ (Note 1)}$	0.3		V
Input High Threshold	VIH(IO)	$I_{IH(MAX)} = \pm 20\mu A \text{ (Note 2)}$		0.7 • V _{CC}	V
Input Low Current	Ι _Ι L			1	mA
Input High Current	lıH			20	μΑ
Output Low Level	V _{OL(IO)}	DATA = GND or DDRV = GND, I_{SINK} = 200 μ A		0.4	V
Output High Level	V _{OH(IO)}	ISOURCE = 20µA	0.8 • V _{CC}		V

ELECTRICAL CHARACTERISTICS (continued)

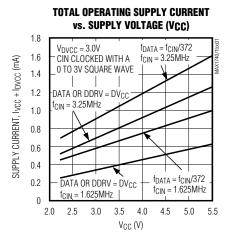
(Figure 1, DV_{CC} = +1.8V, V_{CC} = +3.0V or +5.0V, \overline{SHDN} = DV_{CC}, CIN = RIN = GND or DV_{CC}, IO = V_{CC}, DATA = DDRV = DV_{CC}, CIO = C_{CLK} = C_{RST} = C_{DATA} = 30pF, **T_A** = -40°C to +85°C, unless otherwise noted.) (Note 5)

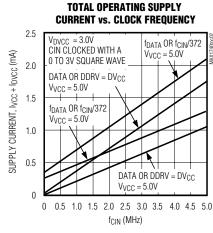
PARAMETER	SYMBOL	COND	MIN	MAX	UNITS	
SHUTDOWN OUTPUT LEVELS				1		
		I _{SINK} = 200µA, SHDN CIN = RIN = DV _{CC} (M.			0.4	V
Shutdown Output Levels (IO, CLK, RST)		I _{SINK} = 200µA, DV _{CC} : (MAX1740) = DDRV (MOX1740) = DDRV (MOX1740) = DV _{CC}			0.4	V
		I_{SINK} = 200 μ A, V_{CC} = GND, \overline{SHDN} (MAX1740) = DDRV (MAX1741) = DATA = CIN = RIN = DV _{CC}			0.4	V
TIMING						
			DV _{CC} = 2.7V	5		
	fCLK	V _{CC} = 2.7V to 5.5V	DV _{CC} = 2.25V	5		
Maximum CLK Frequency (Notes 3, 4)			DV _{CC} = 1.7V	5		MHz
			DV _{CC} = 1.425V	3.5		
		V _{CC} = 2.25V to 3.6V	DV _{CC} = 2.25V	4		
			DV _{CC} = 1.7V	4		
			DV _{CC} = 1.425V	3.5		

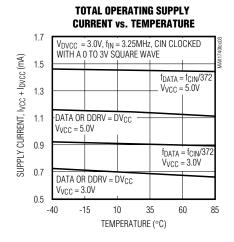
- Note 1: V_{IL} is defined as the voltage at which the output (DATA/IO) voltage equals 0.5V.
- Note 2: VIH is defined as the voltage at which the output (DATA/IO) voltage exceeds the input (IO/DATA) voltage by 100mV.
- Note 3: Timing specifications are guaranteed by design, not production tested.
- **Note 4:** The maximum CLK frequency is defined as the output duty cycle remaining in the 40% to 60% range when the 50% CIN is applied. CIN has 5ns rise and fall times; levels are GND to DV_{CC}. Input and output levels are measured at 50% of the waveform.
- Note 5: Specifications to -40°C are guaranteed by design, not production tested.

Typical Operating Characteristics

(Circuit of Figure 1, DV_{CC} = 3.0V, V_{CC} = 5.0V, DDRV or DATA = DV_{CC}, RIN = CIN = GND, T_A = +25°C, unless otherwise noted.)

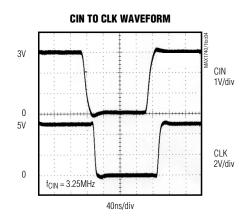


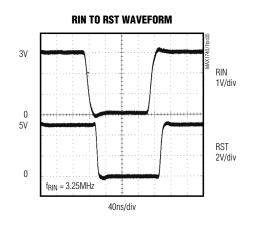


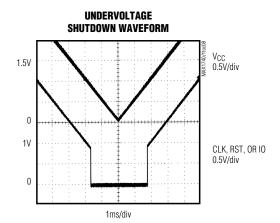


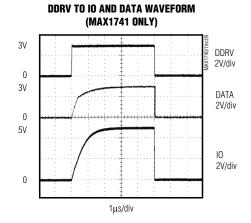
Typical Operating Characteristics (continued)

(Circuit of Figure 1, DV_{CC} = 3.0V, V_{CC} = 5.0V, DDRV or DATA = DV_{CC}, RIN = CIN = GND, T_A = +25°C, unless otherwise noted.)









Pin Description

PIN		NAME	FUNCTION			
MAX1740			FUNCTION			
1	1	DATA	System Controller Data Input/Output. An open-drain input/output with a $20k\Omega$ pull-up resistor to DV _{CC} . For bidirectional data transfer, connect to an open-drain controller output capable of sinking 1mA while pulling DATA low. If the controller is not open drain, use DDRV to send data and DATA to receive data.			
2	2	DV _{CC}	Supply Voltage for System Controller Digital Pins. Set at +1.425V to +5.5V.			
3	3	CIN	System Controller Clock Input			
4	4	RIN	System Controller Reset Input			
_	5	DDRV	Optional System Controller Data Input. Connect to controllers without an open-drain out put. When not used, connect DDRV to DV _{CC} .			
5	_	SHDN	Shutdown Mode Input. Driving SHDN low reduces the total supply current to less than 2µA. In shutdown mode, RST, CLK, and IO are actively pulled low and the transfer gate between DATA and IO is disabled. When not used, connect SHDN to DVcc.			
6	6	GND	System Controller and Card Ground			
7	7	RST	Reset Output to Card. Actively pulled low during shutdown.			
8	8	CLK	Clock Output to Card. Actively pulled low during shutdown.			
9	9	V _{CC}	Supply Voltage for Card-Side Digital Pins. Set at +2.25V to +5.5V. Proper supply bypass ing is required to meet ±10kV ESD specifications.			
10	10	IO	Card-Side Bidirectional Input/Output. An open-drain output with a 10kΩ pull-up resisto V _{CC} . For bidirectional data transfer, connect to an open-drain card output capable of sing 1mA while pulling IO low. Actively pulled low during shutdown.			

Detailed Description

The MAX1740/MAX1741 provide the necessary level translation for interfacing with subscriber identity modules (SIMs) and smart cards in multivoltage systems. These devices operate with logic supply voltages between +1.425V and +5.5V on the controller side (DV_{CC}) and between +2.25V and +5.5V on the card side (V_{CC}). The total supply current (I_{DVCC} + I_{VCC}) is 2.5µA (max) while operating in an idle state (see *Electrical Characteristics*). Figure 2 shows a typical application circuit and functional diagram.

Level Translation

The MAX1740/MAX1741 provide level translators for a clock input, a reset input, and a bidirectional data input/output. The clock and reset inputs (CIN and RIN) are level shifted from the controller-side supply rails (DV $_{\rm CC}$ to GND) to the card-side supply rails (V $_{\rm CC}$ to GND). When connected to an open-drain controller output, DATA and IO provide bidirectional level translation.

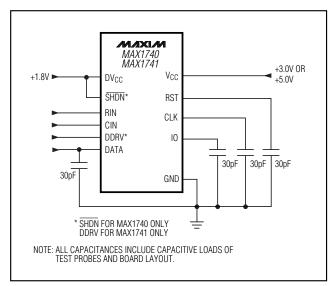


Figure 1. MAX1740/MAX1741 Test Circuit

All level translation is valid for DV_{CC} \geq V_{CC} or DV_{CC} \leq V_{CC}. The MAX1740/MAX1741 contain internal pull-up resistors from DATA to the controller-side supply (DV_{CC}) and from IO to the card-side supply (V_{CC}). For push-pull controller outputs, see the *Data Driver* section for bidirectional data translation.

Data Driver (MAX1741 only)

When using a microcontroller (μ C) without an open-drain output, use the data driver (DDRV) input to send data to the SIM/smart card, while DATA provides the controller-side output for bidirectional data transfer. When not used, connect DDRV to DVCC to reduce total supply current.

Shutdown Mode

For the MAX1740, drive \overline{SHDN} low to activate shutdown. Connect \overline{SHDN} to DV_{CC} or drive high for normal operation. To allow for card insertion and removal, shutdown mode actively pulls CLK, RST, and IO low; it also disconnects the internal 10k Ω pull-up resistor from V_{CC} to prevent excessive current draw. Shutdown mode reduces the total supply current (IDVCC + IVCC) to 0.01 μ A.

SIM/Smart Card Insertion/Removal

The SIM/smart card specifications require that the card-side pins (V_{CC}, CLK, RST, IO) be at ground potential prior to inserting the SIM/smart card. For applications using the MAX1686H (Figure 4), the easi-

est way to achieve this is by shutting down the MAX1686H or by driving SHDN (MAX1740 only) low. If specific sequencing is desired, pull IO low by driving either DATA or DDRV (MAX1741 only) low, and pull CLK and RST low by driving CIN and RIN low, respectively.

ESD Protection

As with all Maxim devices, ESD-protection structures on all pins protect against electrostatic discharges (ESDs) encountered during handling and assembly. For further protection during card insertion and removal, the pins that connect to the card socket (CLK, RST, IO, VCC, and GND) provide protection against ±10kV of ESD, according to the Human Body Model. The ESD structures withstand high ESD in all states: normal operation, shutdown, and power-down. After an ESD event, the MAX1740/MAX1741 continue working without latchup.

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report documenting test setup, test methodology, and test results.

Human Body Model

Figure 3a shows the Human Body Model, and Figure 3b shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of inter-

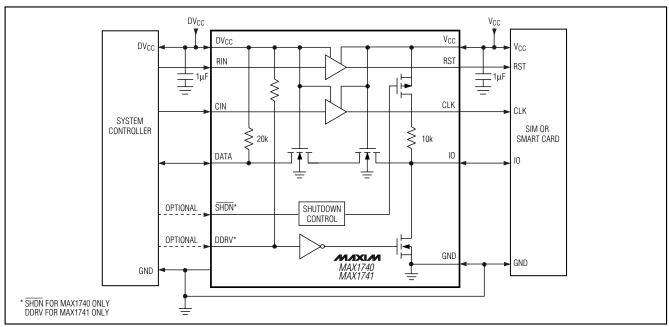


Figure 2. Typical Application Circuit and Functional Diagram

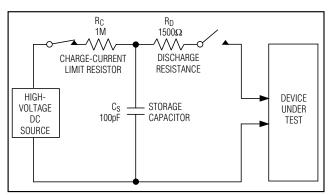


Figure 3a. Human Body ESD Test Model

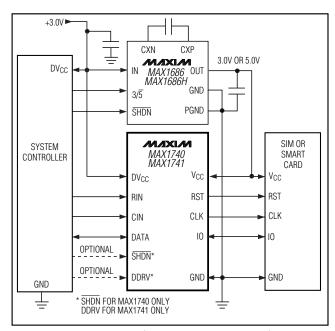


Figure 4. Using MAX1740/MAX1741 and MAX1686/MAX1686H Charge Pump for SIM Card Applications

est, which is then discharged into the test device through a 1.5k $\!\Omega$ resistor.

_Applications Information SIM/Smart Card Interface

To provide 5V when interfacing with a 5V SIM/smart card, 3V systems require a DC-DC converter. The MAX1686H +5V regulating charge pump for SIM cards provides 0V/3V/5V for full compatibility with SIM/smart card specifications. Figure 4 shows the charge pump for SIM card applications. Alternatively, the MAX619 generates a regulated 5V from input voltages as low as 2V.

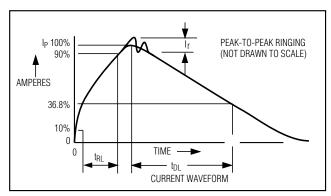


Figure 3b. Human Body Model Current Waveform

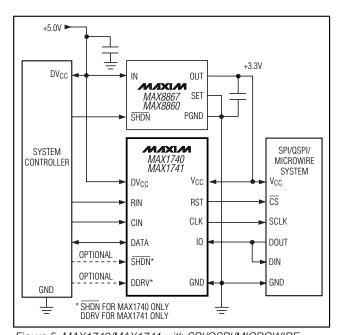


Figure 5. MAX1740/MAX1741 with SPI/QSPI/MICROWIRE Interfaces

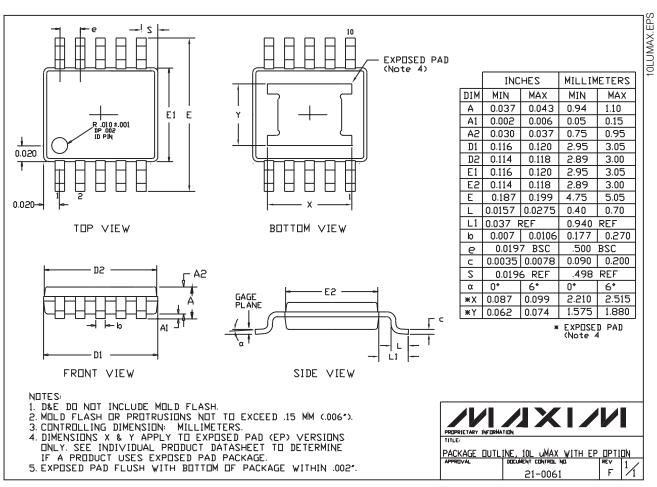
SPI/QSPI/MICROWIRE Interface

The MAX1740/MAX1741 are also useful as 3V/5V level shifters in SPI, QSPI, and MICROWIRE applications (Figure 5). On the slave side, connect CLK to SCLK, RST to $\overline{\text{CS}}$, and IO to DOUT and DIN. The unidirectional level shifters transfer chip select and clock signals to the slave device(s), while the bidirectional level shifter transfers data.

Chip Information

TRANSISTOR COUNT: 114

Package Information



Note: The MAX1740/MAX1741 do not have an exposed pad.

MAX1740/MAX1741

SIM/Smart Card Level Translators in µMAX

NOTES

MAXIM ______ 11

NOTES

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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